

Correction to Transport Characteristics of Multichannel Transistors Made from Densely Aligned Sub-10 nm Half-Pitch Graphene Nanoribbons [ACS Nano 2012, 6, 9700–9710. DOI: 10.1021/nn303127y]. Xiaogan Liang* and Sungjin Wi

An important funding source (NSF Grant No. CMMI-1232883) was accidentally omitted from the acknowledgment section. Below is the corrected acknowledgment. We apologize for the omission.

Acknowledgment. The early stage nanofabrication test was partially supported by the Director, Office of Science, Office of Basic Energy Sciences, Materials Sciences and Engineering Division, of the U.S. Department of Energy under Contract No. DE-AC02-05CH11231. The optimization of the nanofabrication process and the device characterization were finished at the NanoEngineering and NanoDevice Laboratory, University of Michigan (UM), which were supported in part by the new faculty start-up fund from the Department of Mechanical Engineering, University of Michigan, and in part by NSF Grant No. CMMI-1232883. The authors would like to thank Dr. D. Olynick, Dr. S. Cabrini, and Prof. J. Bokor for the helpful discussion during the early concept test at the Molecular Foundry, Lawrence Berkeley National Laboratory; Prof. A. Boehman for his precious advice in revising the manuscript; staffs of the University of Michigan's North Campus Electron Microbeam Analysis Laboratory and NSF Grant No. DMR-0320740 for providing the support of SEM imaging.

Published online August 08, 2013
10.1021/nn4040525